

September 2015

FDC5661N_F085

N-Channel Logic Level PowerTrench[®] MOSFET 60V, 4A, $60 \text{m}\Omega$

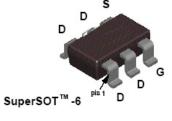
Features

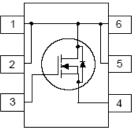
- \blacksquare R_{DS(on)} = 47m Ω at V_{GS} = 10V, I_D = 4.3A
- \blacksquare R_{DS(on)} = 60m Ω at V_{GS} = 4.5V, I_D = 4A
- Typ $Q_{g(TOT)}$ = 14.5nC at V_{GS} = 10V
- Low Miller Charge
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- DC/DC converter
- Motor Drives







MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DSS}	Drain to Source Voltage		60	V
V_{GS}	Gate to Source Voltage	±20	V	
Drain Current Continuous (V _{GS} = 10V)		4.3	^	
I _D	Pulsed		20	Α
E _{AS}	Single Pulse Avalanche Energy (Note 1	1)	81	mJ
P_{D}	Power Dissipation		1.6	W
T _J , T _{STG}	Operating and Storage Temperature		-55 to +150	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case	30	oC/M	
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263, 1in ² copper pad area	а	78	°C/W

Notes:

1: E_{AS} of 81 mJ is 100% test at L = 14mH, I_{AS} = 3.4A, starting T_J = 25°C

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.661N	FDC5661N	SSOT-6	7"	8mm	3000 units

Units

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Parameter

Off Characteristics							
B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS}$	= 0V	60	-	-	V
	Zana Cata Valtana Duain Commant	V _{DS} = 48V,		-	-	1	^
IDSS	Zero Gate Voltage Drain Current	$V_{GS} = 0V$	$T_A = 150^{\circ}C$	-	-	250	μΑ
less	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

Test Conditions

Min

Тур

On Characteristics

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1	2.0	3	V
Prain to Source On Resistance	I _D = 4.3A, V _{GS} = 10V	-	38	47		
	Drain to Source On Resistance	I _D = 4A, V _{GS} = 4.5V	-	46	60	mΩ
'DS(on)		I _D = 4.3A, V _{GS} = 10V T _J = 150°C	-	69	86	11122

Dynamic Characteristics

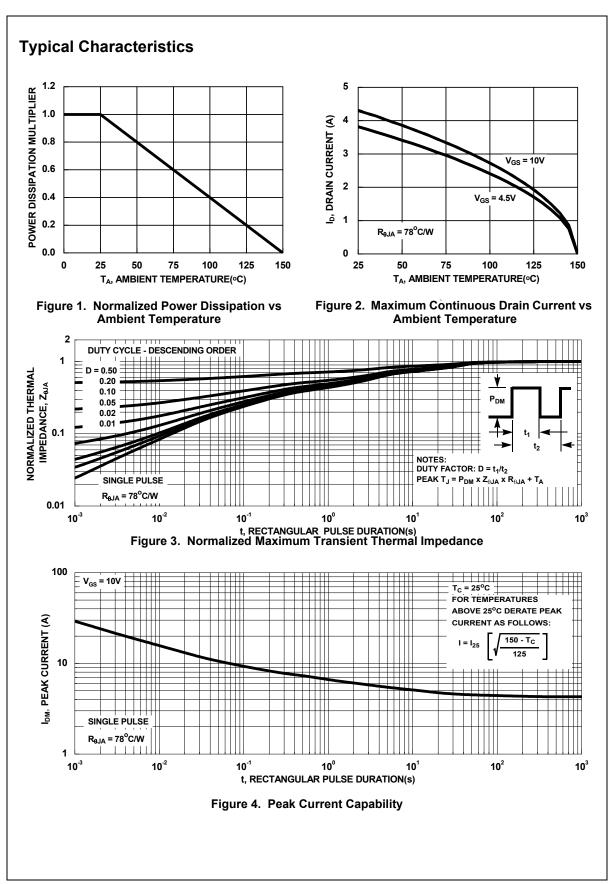
C _{iss}	Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz		-	763	-	pF
Coss	Output Capacitance			1	68		pF
C _{rss}	Reverse Transfer Capacitance			1	36		pF
R_G	Gate Resistance	f = 1MHz		1	2.6		Ω
$Q_{g(TOT)}$	Total Gate Charge at 10V	V _{GS} = 0 to 10V		1	14.5	19	nC
Q_{gs}	Gate to Source Gate Charge		$V_{DD} = 30V$ $I_{D} = 4.3A$	1	2.4		nC
Q_{gd}	Gate to Drain "Miller" Charge	- ID - 4.3A			2.9		nC

Switching Characteristics

t _{on}	Turn-On Time		-	-	17.6	ns
t _{d(on)}	Turn-On Delay Time	.,	-	7.2	-	ns
t _r	Rise Time	$V_{DD} = 30V, I_D = 4.3A$ $V_{GS} = 10V, R_{GS} = 6\Omega$	-	1.6	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10V, K _{GS} = 012	-	19.3	-	ns
t _f	Fall Time		-	3.1	-	ns
t_{off}	Turn-Off Time		-	-	36	ns

Drain-Source Diode Characteristics

		I _{SD} = 4.3A	-	0.8	1.25	
V_{SD}	Source to Drain Diode Voltage	I _{SD} = 2.1A	-	0.8	1.0	_ V
t _{rr}	Reverse Recovery Time	1 - 4 2 4 4 4 4 4 - 400 4 4		18.4	24	ns
Q _{rr}	Reverse Recovery Charge	$I_{SD} = 4.3A$, $dI_{SD}/dt = 100A/\mu s$	-	10.0	13	nC



Typical Characteristics

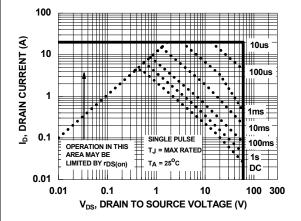


Figure 5. Forward Bias Safe Operating Area

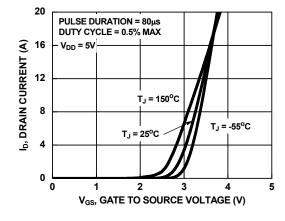


Figure 6. Transfer Characteristics

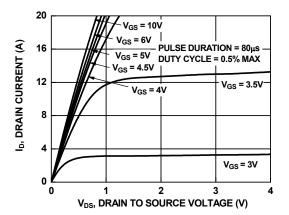


Figure 7. Saturation Characteristics

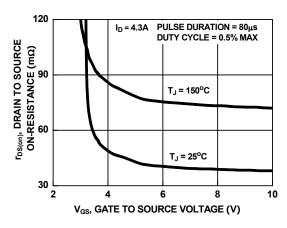


Figure 8. Drain to Source On-Resistance Variation vs Gate to Source Voltage

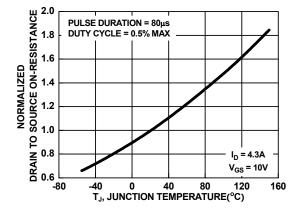


Figure 9. Normalized Drain to Source On Resistance vs Junction Temperature

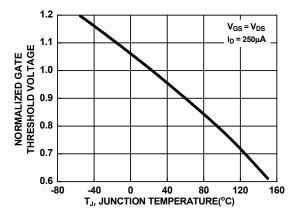


Figure 10. Normalized Gate Threshold Voltage vs Junction Temperature

Typical Characteristics

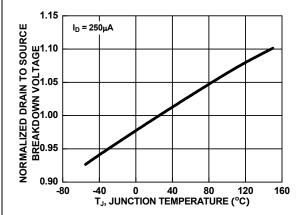


Figure 11. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

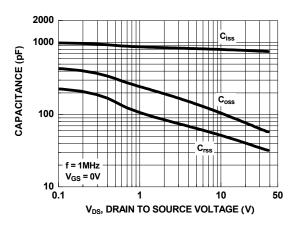


Figure 12. Capacitance vs Drain to Source Voltage
Figure 14.

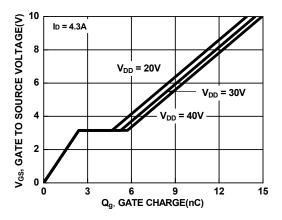
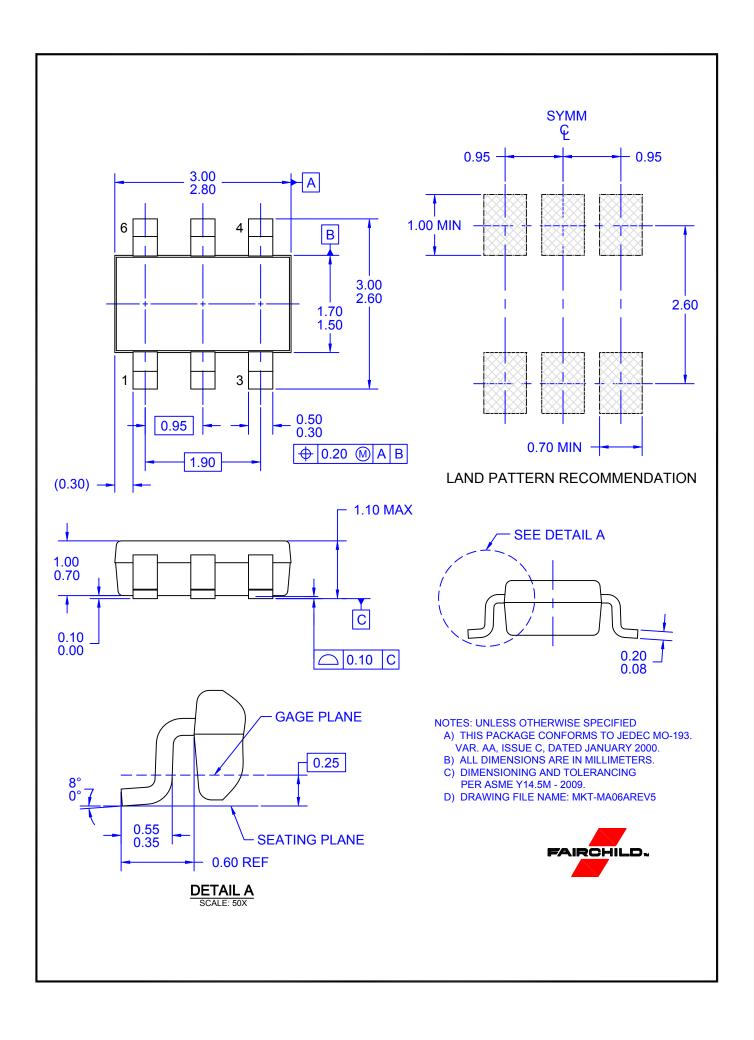


Figure 13. Gate Charge vs Gate to Source Voltage







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Definition of Terms							
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